

This diagram shows a detailed cross-section of a semiconductor device. The main body is a substrate 10, which contains several internal layers and regions. At the top, there are regions labeled 28, 54, 30, 14, 38, 36, 32, 34, 24, 26, and 20. Below these, there are more complex structures including 66, 50, and 22. The bottom part of the device features a layer 16, with regions 52, 64, 65, 56, 58, 60, 62, and 18. On the right side, there are additional regions 12 and 68. Angles α and β are indicated at specific points within the device structure.

A detailed cross-sectional view of a mechanical assembly. The diagram shows a central horizontal shaft or tube (54) passing through a housing. The housing has a complex internal profile with a large, curved, hatched section (56) on the left and a smaller, semi-circular hatched section (65) on the right. The shaft (54) is supported by bearings or guides (58, 60) on the left and a flange or seal (65) on the right. A central vertical line (C) indicates the axis of symmetry. Dimensions L1 and L2 are indicated with arrows, showing the length of specific components. The label BH is located on the right side of the shaft.

FIG. 3a

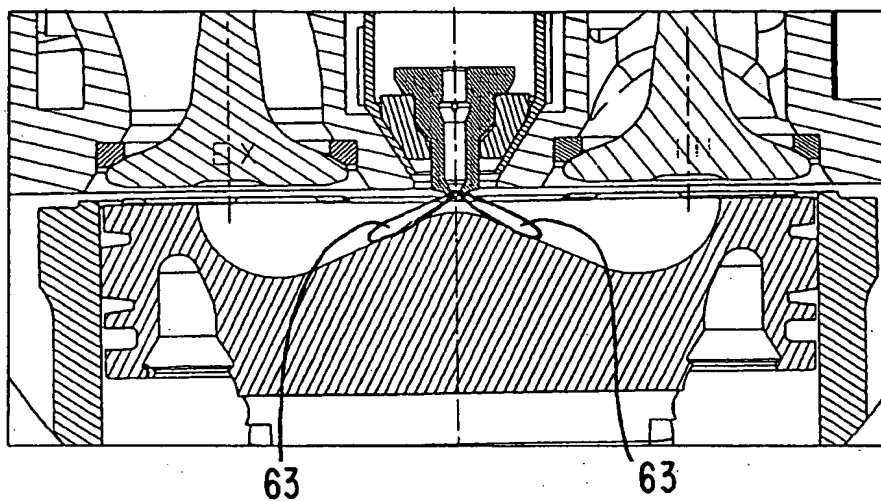


FIG. 3b

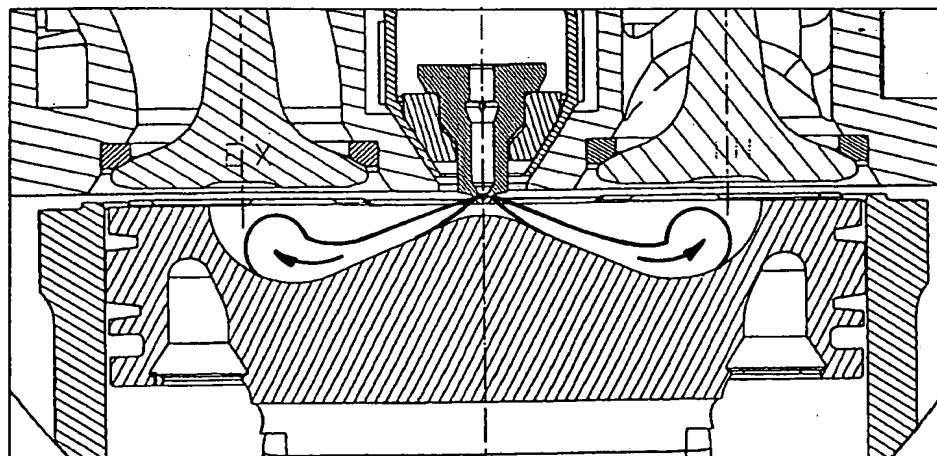
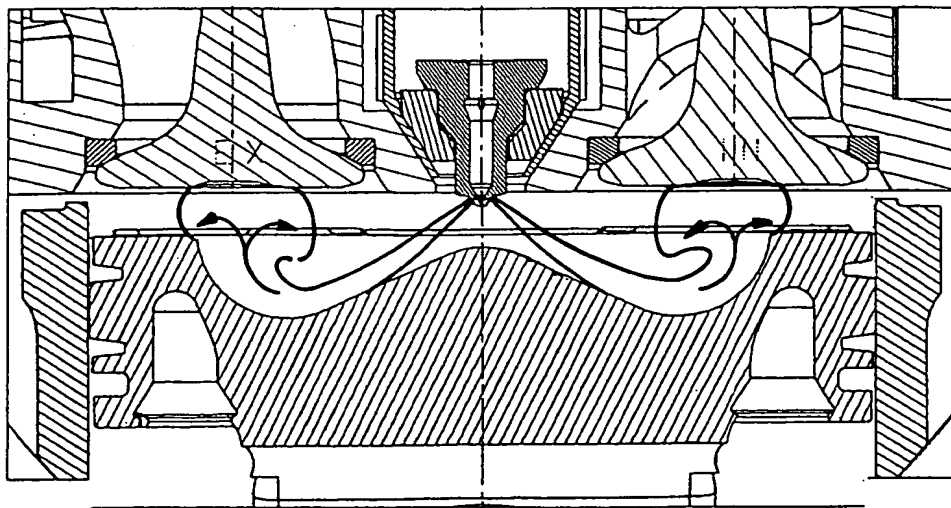


FIG. 3c



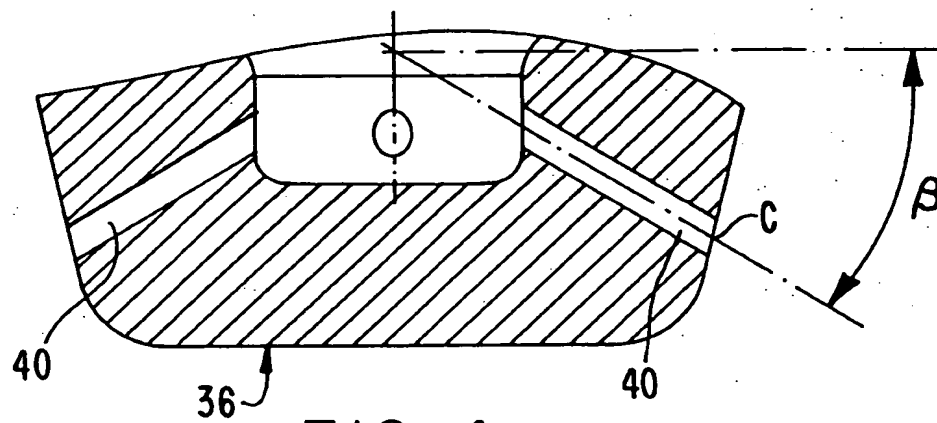


FIG. 4

FIG. 5

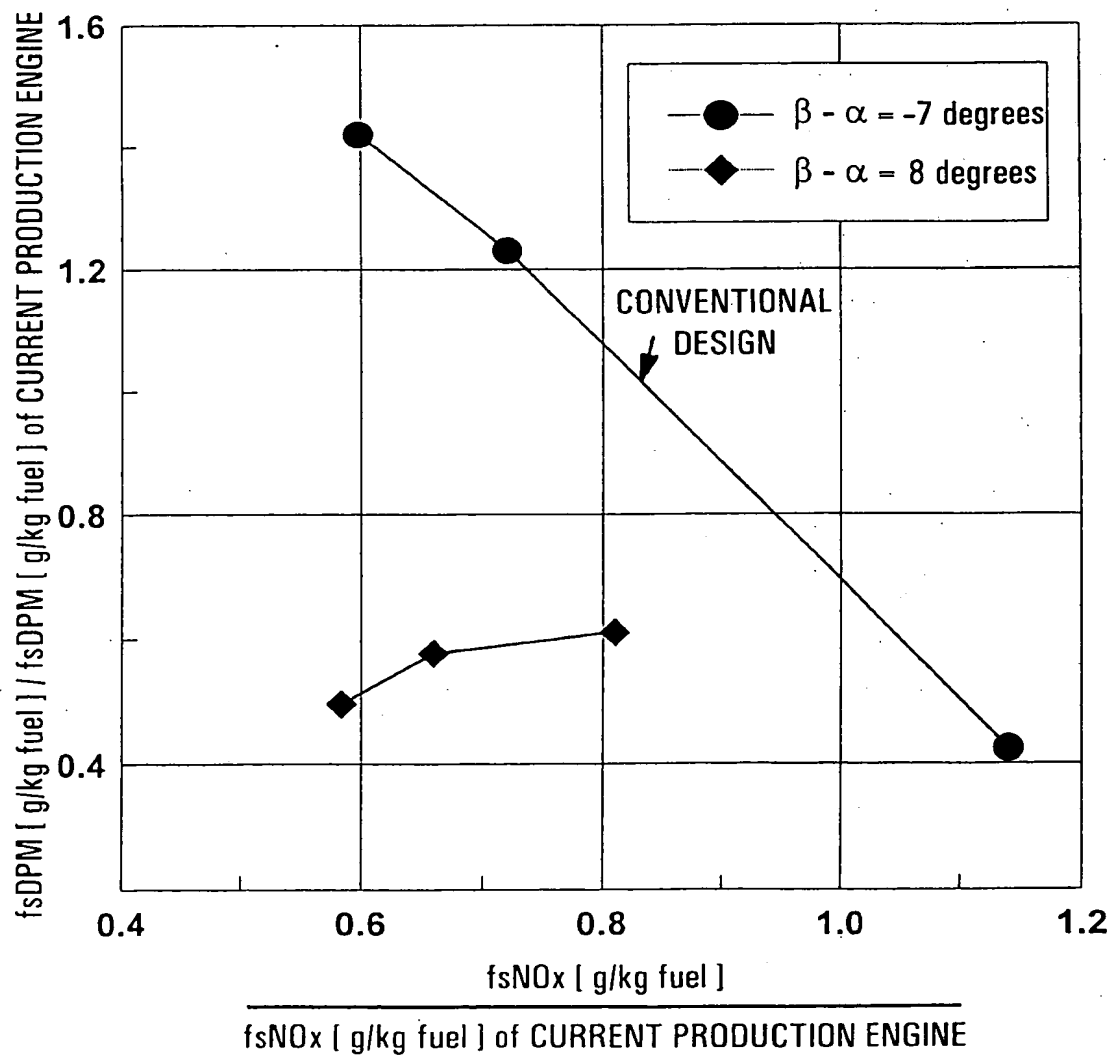


FIG. 6

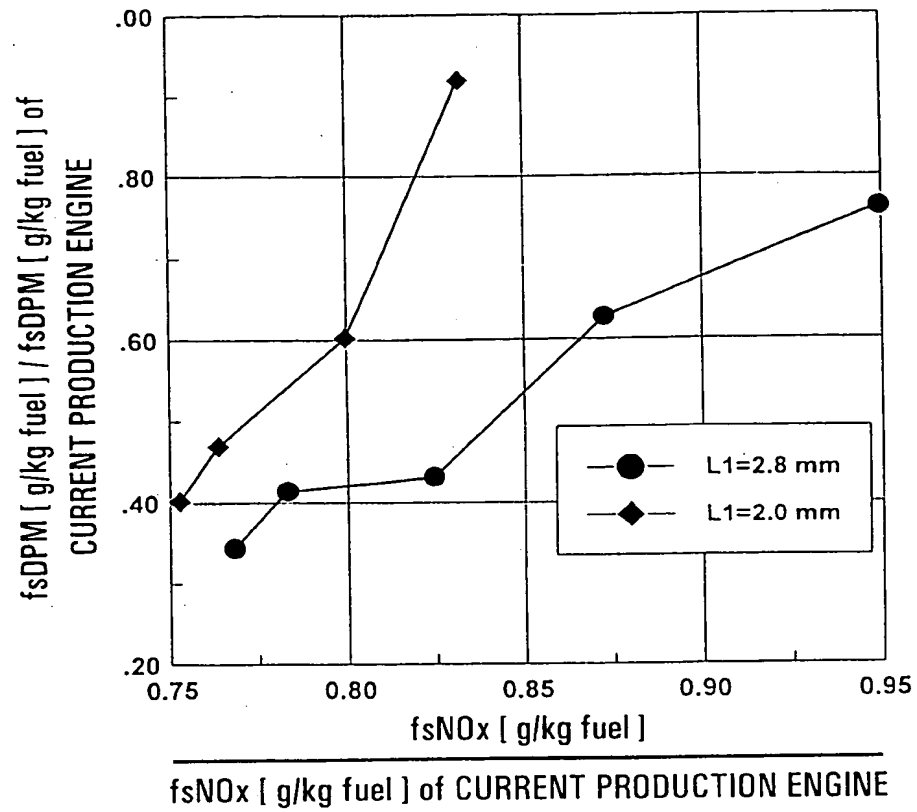


FIG. 7

